

### **INCHANGE SEMICONDUCTOR**

## isc N-Channel MOSFET Transistor

### IPW65R070C6

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### FEATURES

- Static drain-source on-resistance: RDs(on)≤70mΩ
- Enhancement mode:
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

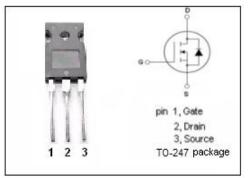
Fast Switching

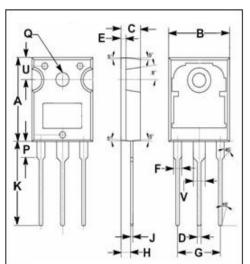
### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT				
V <sub>DSS</sub>	Drain-Source Voltage	650 V					
V <sub>GS</sub>	Gate-Source Voltage	±20	V				
ID	Drain Current-Continuous	53.5	А				
I <sub>DM</sub>	Drain Current-Single Pulsed	150	А				
PD	Total Dissipation @Tc=25°C	391	W				
Tj	Max. Operating Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Temperature	-55~150	°C				

#### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	МАХ	UNIT
Rth(j-c)	Channel-to-case thermal resistance	0.32	°C <b>/W</b>
Rth(j-a)	Channel-to-ambient thermal resistance	62	°C <b>/W</b>









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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	650			V
$V_{GS(th)}$	Gate Threshold Voltage	VDS=VGS; ID=1.76mA	2.5		3.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =17.6A			70	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V; VDS=0V			0.1	mA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V			1	μA
Vsd	Diode forward voltage	I <sub>F</sub> =26.3A, V <sub>GS</sub> = 0V				V

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